

March 2006 Advance Information

FHP3194 4:1 High Speed Multiplexer

Features at ±5V

- 0.1dB gain flatness to 155MHz
- 7.5ns channel switching time
- 0.02%/0.03° differential gain/phase error
- 335MHz full power -3dB bandwidth at G=2
- 1600V/µs slew rate
- 60mA output current (easily drives three video loads)
- 70dB channel to channel isolation
- 13mA supply current
- 4mA supply current in disable mode
- 3mA supply current in shutdown mode
- Fully specified at ±5V supplies
- Lead (Pb) free SOIC-14 and TSSOP-14 packages

Applications

- Video switchers and routers
- Multiple Input HDTV switching
- Picture in picture video switch
- Multi-channel ADC Driver

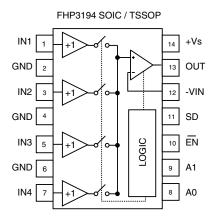
Description

The FHP3194 is a 4:1 analog multiplexer designed for high speed video applications. The output amplifier is a high-speed current feedback amplifier that offers stellar large signal performance of 335MHz -3dB bandwidth and 80MHz 0.1dB bandwidth. The gain of the output amplifier is selectable thru 2 external resistors ($R_{\rm f}$ and $R_{\rm g}$), allowing further flexibility. The $2V_{pp}$ bandwidth performance, $1600V/\mu s$ slew rate, and 0.02% / 0.03° differential gain and phase exceed the requirements of high definition television (HDTV) and other multimedia applications. The output amplifier also provides ample output current to drive multiple video loads.

Two address bits (A0 and A1) are used to select one of the four buffered inputs. The FHP3194 offers excellent 7.5ns switching times and better than 70dB channel isolation.

The FHP3194 offers both shutdown and disable capability. During shutdown, the FHP3194 consumes only 3mA of supply current and provides maximum input to output isolation. During disable mode, only the output amplifier is disabled reducing output glitches and allowing for multiplexer expansion.

Functional Block Diagram

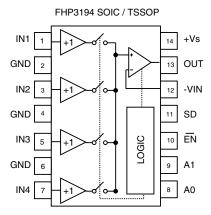


Ordering Information

Part Number	Package	Pb-Free	Operating Temperature Range	Packing Method
FHP3194IM14X	SOIC-14	Yes	-40°C to +85°C	Reel
FHP3194IMTC14X	TSSOP-14	Yes	-40°C to +85°C	Reel

Moisture sensitivity level for all parts is MSL-1.

Pin Configurations



Pin Assignments

Pin#	Pin	Description
1	IN1	Input, Channel 1
2	GND	Must be connected to ground
3	IN2	Input, Channel 2
4	GND	Must be connected to ground
5	IN3	Input, Channel 3
6	-Vs	Negative Supply
7	IN4	Input, Channel 4
8	A0	Logic Input A0
9	A1	Logic Input A1
10	EN	Enable pin, "1" = Disable, "0" = Enable
11	SD	Shutdown pin, "1" = Shutdown, "0" = Active
12	-VIN	Inverting Input of output amplifier
13	OUT	Output
14	+Vs	Positive Supply

Truth Table

A 0	A 1	EN	SD	OUT
1	1	0	0	CH4
0	1	0	0	CH3
1	0	0	0	CH2
0	0	0	0	CH1
Х	Χ	1	0	Disable
Х	Χ	Χ	1	Shutdown

Absolute Maximum Ratings

The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Symbol	Parameter	Min	Max	Unit
V _s	Supply Voltage	0	12.6	V
CMIR	Input Voltage Range	-V _s - 0.5V	+V _s + 0.5V	V

Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit
T _c	Operating Temperature Range	-40		+85	°C
V _s	Supply Voltage Range	5		12	V

Reliability Information

Parameter	Min	Тур	Max	Unit
Junction Temperature			150	°C
Storage Temperature Range	-65		150	°C
Lead Temperature (Soldering, 10s)			300	°C
14-Lead SOIC ¹		128		°C/W
14-Lead TSSOP ¹		130		°C/W

Note:

1. Package thermal resistance (⊙JA), JDEC standard, multi-layer test boards, still air.

ESD Protection

Package	SOIC-14	TSSOP-14
Human Body Model (HBM)	TBD	TBD
Charge Device Model (CDM)	TBD	TBD

Electrical Characteristics at ±5V

 $\rm T_{C}$ = 25°C, $\rm V_{S}$ = ± 5V, $\rm R_{f}$ = 499 $\Omega,$ $\rm R_{L}$ = 150 $\Omega,$ G = 2; unless otherwise noted.

Symbol	Parameter	Conditions	Min	Тур	Max	Units
	Frequency Domain Response					
UGBW	-3dB Bandwidth	$G = +1, V_{OUT} = 0.2V_{pp}$		TBD		MHz
BW _{ss}	-3dB Bandwidth	No Peaking, G = +2, V _{OUT} = 0.2V _{pp}		380		MHz
BW _{Ls}	Full Power Bandwidth	No Peaking, G = +2, V _{OUT} = 2V _{pp}		335		MHz
BW _{0.1dBSS}	0.1dB Gain Flatness	$G = +2, V_{OUT} = 0.2V_{pp}$		155		MHz
BW _{0.1dBLS}	0.1dB Gain Flatness	$G = +2$, $V_{OUT} = 2V_{pp}$		80		MHz
	Time Domain Response					
t _R , t _F	Rise and Fall Time	V _{OUT} = 2V step; (10% to 90%)		1		ns
t _S	Settling Time to 0.1%	V _{OUT} = 2V step		15		ns
OS	Overshoot	V _{OUT} = 0.2V step		5.7		%
SR	Slew Rate	4V step. G = -1		1600		V/µs
	Distortion / Noise Response					
HD2	2nd Harmonic Distortion	2V _{pp} , 5MHz		-70		dBc
HD3	3rd Harmonic Distortion	2V _{pp} , 5MHz		-79		dBc
THD	Total Harmonic Distortion	2V _{pp} , 5MHz		-81		dB
DG	Differential Gain	NTSC (3.58MHz)		0.02		%
DP	Differenital Phase	NTSC (3.58MHz)		0.03		0
e _n	Input Voltage Noise	> 1MHz		7		nV/Hz
i _{n+}	Input Current Noise (+)	> 1MHz		22		pA/Hz
i _{n-}	Input Current Noise (-)	> 1MHz		16		pA/Hz
X _{TALK}	All Hostile Crosstalk	Channel-to-channel 5MHz/30MHz		-85 / -65		dB
	DC Performance					
V _{IO}	Input Offset Voltage ¹		-9	1	+9	mV
dV _{IO}	Average Drift			8.5		μV/°C
V _{IOM}	Input Offset Voltage Matching ¹	Channel to channel	-5	TBD	5	mV
I _{bn}	Input Bias Current non-inverting ¹	Pins 1,3,5,7	-16	4	16	μА
dl _{bn}	Average Drift			16		nA/°C
I _{bi}	Input Bias Current inverting ¹	Pin 12	-20	13	20	μА
dl _{bn}	Average Drift			85		nA/°C
GM	Gain Matching	Channel-to-channel		0.05		%
PSRR	Power Supply Rejection Ratio ¹	DC	54	60		dB
I _S	Supply Current ¹			13	18	mA
I _{EN}	Disable Supply Current ¹	Disable Mode		4	6	mA
I _{SD}	Shutdown Supply Current ¹	Shutdown Mode		3	5	mA
	Switching Characteristics					
	Switching Time	Channel-to-Channel				
	50% Logic to 10% Output Settling	IN0, IN2 = +0.5V; IN1, IN3 = -0.5V		7.5		ns
	50% Logic to 10% Output Settling	IN0, IN2 = +0.5V; IN1, IN3 = -0.5V		9.1		ns
	50% Logic to 10% Output Settling	IN0, IN2 = +0.5V; IN1, IN3 = -0.5V		25		ns
	Channel Switching Transient (Glitch)	All inputs grounded		104		mV _{pp}

Notes:

1. 100% tested at 25°C

Electrical Characteristics at ±5V continued

 $\rm T_{c}$ = 25°C, $\rm V_{s}$ = ±5V, $\rm R_{f}$ = 499 $\Omega,$ $\rm R_{L}$ = 150 $\Omega,$ G = 2; unless otherwise noted.

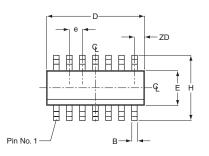
Symbol	Parameter	Conditions	Min	Тур	Max	Units
	Digital Inputs					
V _{IH}	Logic High Threshold	A0, A1, EN, and SD pins	2.0			٧
V _{IL}	Logic Low Threshold	A0, A1, EN, and SD pins			0.08	٧
I _{IH}	Logic Pin Input Current High	A0, A1, EN, and SD pins; Logic Input = 2.0V		TBD		μА
I _{IL}	Logic Pin Input Current Low	A0, A1, EN, and SD pins; Logic Input = 0V		TBD		μА
	Disable Characteristics					
EN _{ISO}	Disable Isolation	5MHz / 30MHz		-88 / -72		dB
SD _{ISO}	Shutdown Isolation	5MHz / 30MHz		-92 /-77		dB
CH _{ISO}	Channel-to-Channel Isolation	5MHz		-70		dB
ENT _{ON}	Turn on time (Disable to ON)			17		ns
ENT _{OFF}	Turn off time (ON to Disable)			120		ns
SDT _{ON}	Turn on time (Shutdown to ON)			20		ns
SDT _{OFF}	Turn off time (On to Shutdown)			115		ns
	Input Characteristics					
R _{IN}	Input Resistance			TBD		ΜΩ
C _{IN}	Input Capacitance			TBD		pF
CMIR	Input Common Mode Voltage Range			±2.8		V
CMRR	Common Mode Rejection Ratio ¹	DC, V _{CM} = ±1V	50	52		dB
	Output Characteristics					
V	Output Voltage Swing ¹	$R_L = 2k\Omega$		±3.8		V
V _O	Output voltage Swing	$R_L = 150\Omega$	±3.2	±3.7		V
I _{OUT}	Linear Output Current			±60		mA
I _{SC}	Short Circuit Output Current	V _O = GND		±100		mA
D	Output Basistanas	enabled		TBD		mΩ
R _{OUT}	Output Resistance	disabled		TBD		ΜΩ
C _{OUT}	Output Capacitance			TBD		pF

Notes:

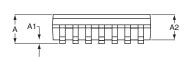
1. 100% tested at 25°C

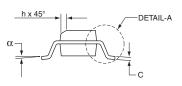
Mechanical Dimensions

14-Lead Small Outline Package (SOIC)









SOIC-14				
SYMBOL	MIN	MAX		
A1	.0040	.0098		
В	.014	.018		
С	.0075	.0098		
D	.337	.344		
E	.150	.157		
е	.050	BSC		
Н	.2284	.2440		
h	.0099	.0196		
L	.016	.050		
Α	.060	.068		
	0°	8°		
ZD	0.20 ref			
A2	.054	.062		

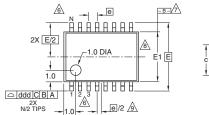
NOTE:

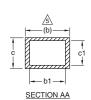
- 1. All dimensions are in inches.
- 2. Lead coplanarity should be 0 to 0.10mm (.004") max.

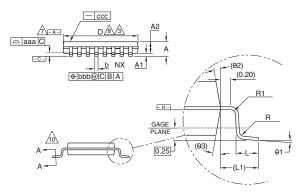
- 2. Lead coplanarity should be 0 to 0.10mm (.004) ma.

 3. Package surface finishing:
 (2.1) Top: matte (charmilles #18~30).
 (2.2) All sides: matte (charmilles #18~30).
 (2.3) Bottom: smooth or matte (charmilles #18~30).
- 4. All dimensions excluding mold flashes and end flash from the package body shall not exceed o.152mm (.006) per side (d).

14-Lead Outline Package (TSSOP)







155UP-14					
SYMBOL	MIN	NOM	MAX		
Α	-	-	1.10		
A1	0.05	-	0.15		
A2	0.85	0.90	0.95		
L	0.50	0.60	0.75		
R	0.09	_	-		
R1	0.09	_	-		
b	0.19	_	0.30		
b1	0.19	0.22	0.25		
С	0.09	_	0.20		
c1	0.09	_	0.16		
0 1	0°	_	8°		
L1		1.0 REF			
aaa		0.10			
bbb		0.10			
CCC		0.05			
ddd		0.20			
е		0.65 BSC			
0 2		12° REF			
0 3	12° REF				
D	4.90	5.00	5.10		
E1	4.30	4.40	4.50		
Е	6.4 BSC				
е	0.65 BSC				
N		14			

TSSOP-14

NOTES:

- 1 All dimensions are in millimeters (angle in degrees).
- 2 Dimensioning and tolerancing per ASME Y14.5-1994.
- 🔬 Dimensions "D" does not include mold flash, protusions or gate burrs. Mold flash protusions or gate burrs shall not exceed 0.15 per side .
- 🛕 Dimension "E1" does not include interlead flash or protusion. Interlead flash or protusion shall not exceed 0.25 per side.
- 🖄 Dimension "b" does not include dambar protusion. Allowable dambar protusion shall be 0.08mm total in excess of the "b" dimension at maximum material condition. Dambar connot be located on the lower radius of the foot. Minimum space between protusion and adjacent lead is 0.07mm for 0.5mm pitch packages.
- A Terminal numbers are shown for reference only.
- \triangle Datums -A- and -B- to be determined at datum plane -H-.
- Dimensions "D" and "E1" to be determined at datum plane
 ☐ H —.
- htis dimensions applies only to variations with an even number of leads per side. For variation with an odd number of leads per side, the "center" lead must be coincident with the package centerline, Datum A.
- Cross sections A A to be determined at 0.10 to 0.25mm from the leadtip.

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx TM ActiveArray TM Bottomless TM Build it Now TM CoolFET TM CROSSVOLT TM DOME TM EcoSPARK TM E ² CMOS TM EnSigna TM FACT TM FACT Quiet Series	FAST® FASTr™ FPS™ FRFET™ GlobalOptoisolator™ GTO™ HiSeC™ ²C™ i-Lo™ ImpliedDisconnect™ IntelliMAX™	ISOPLANAR TM LittleFET TM MICROCOUPLER TM MicroPak TM MICROWIRE TM MICROWIRE TM MSX TM MSXPro TM OCX TM OCXPro TM OPTOLOGIC [®] OPTOPLANAR TM	PowerSaver TM PowerTrench [®] QFET [®] QS TM QT Optoelectronics TM Quiet Series TM RapidConfigure TM RapidConnect TM µSerDes TM ScalarPump TM SILENT SWITCHER [®] SMART START TM	SuperSOTTM-6 SuperSOTTM-8 SyncFETTM TCMTM TinyLogic® TINYOPTOTM TruTranslationTM UHCTM UltraFET® UniFETTM VCXTM WireTM
	l. Around the world.™ chise [®]	PACMAN TM POP TM Power247 TM PowerEdge TM	SPM TM Stealth TM SuperFET TM SuperSOT TM -3	VIIIC

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. I18